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INFORMATION DISCHASLIBE A				Z	Application Number	10/080,789		
STATEMENT BY APPLICATION OF STATEMENT BY APPLICATION OF STATEMENT BY APPLICATION (use as many sheets as necessary)					Filing Date	February 21, 2002		
					First Named Inventor	Staple, Bevan	BECEN	·
					Art Unit	2661	THEFEIN	ED
					Examiner Name	Not Yet Known	JUL 0 3	000
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		OTHER PRIOR ART NON PATENT LITERATURE DOCUMENTS			
Examiner Cite No.1		Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.			
all	BC ,	AKIYAMA, TERUNOBU, et al., "Controlled Stepwise Motion in Polysilicon Microstructures," Journal of Microelectromechanical Systems, Vol. 2., No. 3, pp. 106-110, September 1993			
an	BD	ASHRUF, C.M.A., et al., "Galvanic porous silicon formation without external contacts," Sensors and Actuators 74, pp. 118-122, 1999			
ay	BE	BEAN, KENNETH E., "Anisotropic Etching of Silicon," IEEE Transactions on Electron Devices, Vol. ED-25, No. 10, pp. 1185-1193, October 1978			
OH	BF	CIARLO, DINO R., "A latching accelerometer fabricated by the anisotropic etching of (110) oriented silicon wafers,"			
ay	BG	KAAJAKARI, VILLE, et al., "Ultrasonic Actuation for MEMS Dormancy-Related Stiction Reduction," Proceedings of SPIE Vol. 4180, 2000			
ay	вн	KOCH, T., et al., "Anisotropically etched deep gratings for InP/InGasAsP Optical devices," J. Appl. Phys. 62 (8),			
all	ВІ	SCHILLING, M., et al., "Deformation-free overgrowth of reactive ion beam etched submicron structures in InP by liquid phase epitaxy," Appl. Phys. Letter 49 (12) September 1986			
ay	ВЈ	TANG, WILLIAM C., et al., "Electrostatically Balanced Comb Drive for Controlled Levitation," Technical Digest IEEE Solid-State Sensor and Actuator Workshop, pp. 23-27, June 1990			
041	вк	TORCHEUX, L., et al., "Electrochemical Coupling Effects on the Corrosion of Silicon Samples in HF Solutions," J. Electrochem. Soc. Vol. 142, No. 6, June 1995			
04.	BL	VAN KESSEL, PETER F. et al, "A MEMS-Based Projection Display," Proceedings of the IEEE, Vol. 86, No. 8, pp. 1687-1704, August 1998			
041	вм	MULLER, LILAC, "Gimballed Electrostatic Microactuators with Embedded Interconnects," Dissertation, Spring 2000			
24	BN	KELLER, CHRISTOPHER GUILD, "Microfabricated Silicon High Aspect Ratio Flexures for In-Plane Motion," Dissertation, Fall 1998	\dashv		

			
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•_			77, 183

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